NONTRIVIAL QUANTUM OSCILLATION GEOMETRIC PHASE SHIFT IN A TRIVIAL BAND

Mandar M. Deshmukh DCMP and MS TIFR, Mumbai, India

Datta et al. Science Advances 5, eaax6550 (2019). Datta et al. Physical Review Letters 121, 056801 (2018),

Support from Department of Atomic Energy and Department of Science and Technology of India

ICTS-TIFR Bengaluru 23rd January 2020

www.tifr.res.in/~nano

Collaborators

Biswajit Datta, Pratap Chandra Adak, Hitesh Agarwal Li-kun Shi (NTU Singapore), **Justin Song (NTU Singapore)**

Kenji Watanabe (NIMS, Japan), Takashi Taniguchi (NIMS Japan)

Outline

- Few layers of graphene why are they interesting?
- Trilayer ABA graphene
- Measuring quantum oscillations
- Berry's phase in a multiband system

Graphene basics



$$H_{\boldsymbol{K}} = v_F \boldsymbol{\sigma} \cdot \boldsymbol{p}$$
$$H_{\boldsymbol{K}'} = -H_{\boldsymbol{K}'}$$

Bravais lattice with two carbon atom basis



Why few layers of graphene are interesting?



- Interactions become more important for multiple layers due to flatter bands
- Tunable symmetries
- Possibility of studying non-Abelian quantum Hall states

Breaking inversion symmetry in bilayer graphene opens up a bandgap

Bilayer graphene



Zhang et al. Nature 459, 820 (2009).

Tuning topological properties



ABC trilayer, Chittari et al. PRL 122, 016401 (2019)

Outline

- Few layers of graphene why are they interesting?
- Trilayer ABA graphene
- Measuring quantum oscillations
- Berry's phase in a multiband system

ABA-Trilayer Graphene: Crystal and Band Structure



Monolayer graphene (MLG)-like and bilayer graphene (BLG)-like bands

Bands do not hybridize at the crossing points due to mirror symmetry protection

Some states are polarized in mirror symmetric and anti-symmetric basis

Effect of Electric Field on the Band Structure



Electric field increases the band gap of MLG-like bands

Understanding our experimental system



- Mobility ~ 800,000 cm² V⁻¹ s⁻¹
- Mean free path \sim 10 μ m

• Average
$$E^{\perp}=2\Delta_1/d$$
 (e)



Landau levels



- Monolayer-like Landau Level gaps are much larger than bilayer-like bands
- Zeroth Monolayer-like Landau Level does not disperse with magnetic field

Biswajit Datta et al. Physical Review Letters 121, 056801 (2018).

Outline

- Few layers of graphene why are they interesting?
- Trilayer ABA graphene
- Breaking mirror symmetry
- Measuring quantum oscillations
- Berry's phase in a multiband system

Berry's phase



- A version of this for optics proposed by Panchratnam
- The flux enclosed by the closed loop due to the Berry's curvature
- In a periodic lattice depends on symmetry of the lattice

Semiclassical quantization and Berry's phase



Mikitik and Sharlai Phys. Rev. Lett. 82 2147 (1999)

SdH Oscillations

- Magnetoresistance oscillations reflecting density of states oscillations
- de Haas van Alphen can be used as it is essentially the same physics

 $\Delta R_{xx} = R(B, T) \cos[2\pi (B_{\rm F}/B + 1/2 + \beta)]$



Zhang et al. Nature **438**, 201 (2005).

Connection to trilayer physics

Gapped monolayer like levels and gapped bilayer like levels exist in trilayer ABA graphene



Multiband magnetotransport



- Two SdH frequency results from two Fermi surfaces
- Phase of the BLG-like oscillations depend on the MLG-like band gap!
- Changing phase is not Berry's phase of the bilayer band

18

Anomalous SdH phase shift measured in trivial band





 Phase changes continuously close to the band gap!

How does one understand the anomalous SdH phase shift?

$$\Delta G_{XX} = G_M \cos \left[2\pi \left(\frac{B_{FM}}{B} + \Upsilon_M \right) \right] + G_B \cos \left[2\pi \left(\frac{B_{FB}}{B} + \Upsilon_B \right) \right]$$

$$B_{FM} = \frac{n_M h}{4e} \qquad B_{FB} = \frac{n_B h}{4e}$$

$$\Delta G_{XX} \approx G_B \cos \left[2\pi \left(\frac{B_{FB}}{B} + \Upsilon_B \right) \right]$$

$$B_{FB} = \frac{n_B h}{4e} = \frac{(n_T - n_M) h}{4e} = B_{FT} - \frac{\nabla_M B}{4}$$

$$\Delta G_{XX} \approx G_B \cos \left[2\pi \left(\frac{B_{FT}}{B} + \Upsilon_B - \frac{\nabla_M}{4} \right) \right]$$

$$Below the gap v_M = -2$$

$$\Delta G_{XX} \approx G_B \cos \left[2\pi \left(\frac{B_{FT}}{B} + \Upsilon_B - \frac{\nabla_M}{4} \right) \right]$$

$$In the gap v_M = 0$$

$$\Delta G_{XX} \approx G_B \cos \left[2\pi \left(\frac{B_{FT}}{B} + \Upsilon_B - \frac{1}{2} \right) \right]$$

$$\Delta G_{XX} \approx G_B \cos \left[2\pi \left(\frac{B_{FT}}{B} + \Upsilon_B - \frac{1}{2} \right) \right]$$

Datta et al. arXiv:1902.04264 (to appear in Science Advances).

SdH frequency -- area of Fermi Surface and filling enforcement



Independent corroboration of the phase shift from the measurement of Fermi surface area

Outline

- Few layers of graphene why are they interesting?
- Trilayer ABA graphene
- Breaking mirror symmetry
- Measuring quantum oscillations
- Berry's phase in a multiband system

Science Advances 5, eaax6550 (2019). Physical Review Letters 121, 056801 (2018)